

Large dielectric constant and giant nonlinear conduction in the organic conductor (BEDT-TTF)₂CsZn(SCN)₄

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The dielectric constant and ac conductivity have been measured for the layered organic conductor (BEDT-TTF)₂CsZn(SCN)₄ along the out-of-plane direction, which show a relaxation behavior similar to those in the charge-density-wave conductor. Most unexpectedly, they exhibit a large bias dependence with a hysteresis, and changes in magnitude by 100-1000 times at a threshold. These findings are very similar to the collective excitation of the charge density wave. (BEDT-TTF)₂CsZn(SCN)₄ has collective excitations associated with charge ordering, though it shows no clear indication of long range order.

I. INTRODUCTION

There appear growing interests in the self-organization phenomena of conduction electrons, known as charge inhomogeneity. A prime example is the high-temperature superconducting copper oxides, in which the nano-scale phase-separation of doped carriers is observed in scanning-tunnel-microscope experiments [1]. Another example is the charge order (CO) in the transition-metal oxides [2, 3], where spins and holes are alternately aligned to form a charge-density-wave (CDW) order and a spin-density-wave (SDW) order simultaneously. These have been regarded as a new aspect of strongly correlated electron systems, because the electrons tend to be self-organized in order to minimize the magnetic energy of the background spins. Thus we expect that such a self-organization will happen regardless of the degrees of disorder, and call it "intrinsic inhomogeneity". In real materials, however, disorder-driven effects cannot be ruled out, owing to unavoidable solid solutions and defects. But rather, there increase a number of papers reporting that the charge order is quite susceptible to disorder [4]. Thus, to search for intrinsic charge inhomogeneity, we need a charge-ordered system in a very clean solid.

Organic salts are a good candidate for the clean system. They are grown in organic solvent at room temperature, where the thermal energy is small enough to suppress point defects. Actually most of the metallic salts exhibit the Shubnikov-de Haas oscillation at low temperatures [5]. This means that the mean free path of the conduction electron is very long, and that

the crystal is free from impurities. In particular, the BEDT-TTF [bis(ethylenedithio)-tetrathiafulvalene] salts are most suitable for the study of the strong correlation in two dimension, and the (BEDT-TTF) salts have been most thoroughly investigated among them, where a superconductor-antiferromagnetic insulator transition takes place by changing hydrostatic pressure, anion species, and deuterium substitution [6, 7].

(BEDT-TTF)₂MZn(SCN)₄ (M = Rb and Cs) is another interesting family of the BEDT-TTF salts [8, 9], where the BEDT-TTF molecules form a distorted triangular lattice. The BEDT-TTF layer acts as a two-dimensional conducting layer, and owing to the triangular stacking, a single elliptic Fermi surface is calculated in the tight-binding approximation. This makes a remarkable contrast with the type salts, in which the BEDT-TTF molecules form a dimer to make two Fermi surfaces (the electron pocket and the one-dimensional sheet). In this sense, the type salts are a truly two-dimensional system with a moderate in-plane anisotropy. Another feature is that they are quarter-filled (one hole for the two BEDT-TTF molecules), which means that the system is far from the Mott transition that occurs near half-filling [10]. The most interesting feature is that they are unstable against CO along the c axis [11]. A metal-insulator transition due to CO occurs at T_{MI} = 190 K for (BEDT-TTF)₂RbZn(SCN)₄ (the M = Rb salt) [8].

The dielectric constant is a good probe for the charge inhomogeneity. We have studied the dielectric response of strongly correlated systems, and have found a large dielectric constant above T_{MI} for the M = Rb salt [12]. The frequency dependence is quantitatively explained in terms of a generalized formula of Debye's dielectric relaxation, which strongly suggests that fractions of CO already exist even at room temperature. Such a picture is consistent with other measurements such as NMR [13]

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and optical reactivity [14]. This is a piece of evidence that the charge inhomogeneity can occur in a homogeneous system. In this paper, we report on the dielectric response and the nonlinear conductivity of $(\text{BEDT-TTF})_2\text{CsZn}(\text{SCN})_4$ (the $M = \text{Cs}$ salt) single crystals. We have found anomalously large nonlinear conductivity just like the sliding of CDW, although there is no sign for CDW/SDW transitions at all temperatures. This implies that the $M = \text{Cs}$ salt exhibits a collective excitation without long range order.

II. EXPERIMENTAL

Single crystals with a typical dimension of $2 \times 0.2 \times 0.2 \text{ mm}^3$ were prepared using a galvanostatic anodic oxidation method, and the detailed growth conditions and their characterization were described in [8].

The resistivity was measured by a four-probe and two-probe method from 4.2 to 300 K in a liquid He cryostat. The contact resistance was 10-50 Ω at room temperature. Thus the resistivity obtained by the two-probe method was accurate within an error bar of 1% at all the temperatures for the out-of-plane direction (the b-axis direction), and below 10 K for the in-plane direction (the a-axis direction).

The dielectric constant (ϵ_b) and ac conductivity (σ_b) along the out-of-plane direction (the b direction) were measured with a parallel plate capacitor arrangement using an ac two-contact four-probe method with an LCR meter (Agilent 4284A, and 4286A) from 10^3 to 10^6 Hz . The dc-bias dependence of ϵ_b and σ_b was also measured in the static dc voltage. The in-plane dielectric constant was not measured, because it had too low resistance for us to measure ϵ precisely. Owing to the two-contact configuration, the contact resistance and capacitance might have affected the measurement. As mentioned, the contact resistance was negligible along the out-of-plane direction, which was verified by the fact that the observed σ_{ac} was quantitatively consistent with the observed dc resistivity for $\epsilon \gg 0$. Though we did not evaluate the contact capacitance, we can employ an evaluated value of 500 pF for La_2CuO_4 from Ref. [15], because the contact capacitance is primarily determined by the area of the contact. It gives a reactance of 3×10^5 at 1 kHz, which is 10^4 times larger than the contact resistance. As a result, we can safely assume that our contact is primarily a resistive coupling, and can neglect the contact capacitance. We should further note that we tested different contact configurations of other samples, and found that the results were reproducible within experimental errors.

III. RESULTS

Figure 1(a) shows $\epsilon_b(\omega)$ of the $M = \text{Cs}$ salt. Reflecting the insulating behavior, the dielectric response is far from Drude-like: ϵ_b shows a positive sign, and decreases with

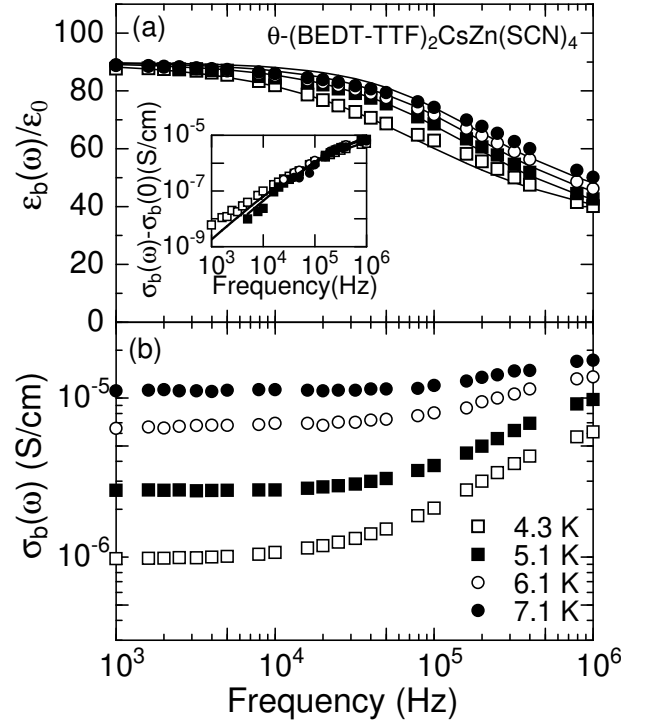


FIG. 1: (a) Dielectric constant and (b) ac conductivity of $(\text{BEDT-TTF})_2\text{CsZn}(\text{SCN})_4$ along the out-of-plane (the b axis) direction

increasing frequency. The magnitude is as large as 90 at low frequencies, and such a large ϵ is rarely observed in conventional insulators. The large value of 90 is gradually relaxed to a small value of 40 at high frequencies, which can be explained in terms of a generalization of Debye's dielectric relaxation (the Havriliak-Negami formula [16]) given by

$$\epsilon(\omega) = \epsilon_{HF} + \frac{\epsilon_{LF} - \epsilon_{HF}}{[1 + (i\omega\tau)^1]^{-1}} \quad (1)$$

where ϵ_{LF} and ϵ_{HF} are dimensionless parameters, and satisfy $0 < \epsilon_{LF} < \epsilon_{HF} < 1$. ϵ_{LF} and ϵ_{HF} are the low- and high-frequency dielectric constants, and τ is the relaxation time. The fitting results are shown by the solid curves in Fig. 1(a), which satisfactorily fit the measured data. All the parameters except for τ are independent of temperature, which will be discussed in the next section.

Figure 1(b) shows $\sigma_b(\omega)$ of the $M = \text{Cs}$ salt. As is similar to ϵ_b , the frequency dependence suggests relaxation behavior: A small value of σ_b at low frequencies gradually increases to a higher value at high frequencies. Note that σ_b has a finite value for $\omega \rightarrow 0$, which cannot be ascribed to the dielectric relaxation. In general, σ_b is expressed as the sum of the dc and ac parts given by

$$\sigma_b(\omega) = \sigma_{dc}(\omega) + \sigma_{ac}(\omega; T) \quad (2)$$

σ_{dc} is derived from the overdamped Drude contribution. As is well known, the Drude conductivity σ_D is written

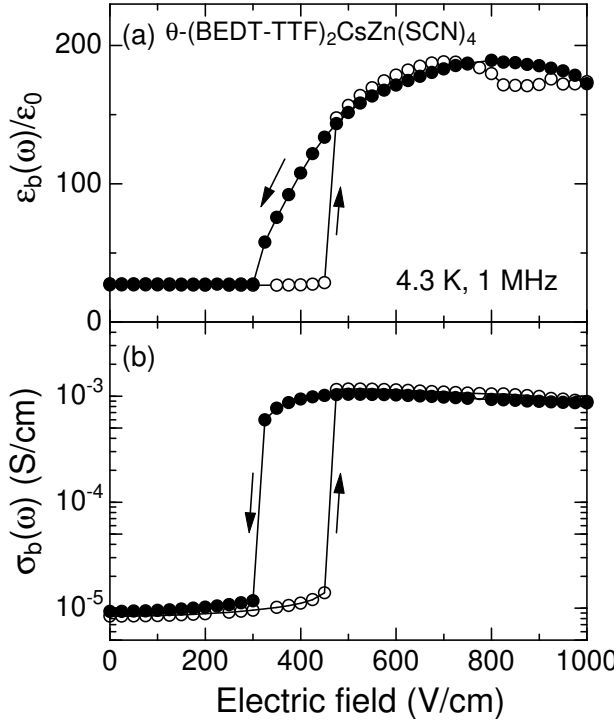


FIG. 2: (a) Dielectric constant and (b) ac conductivity of $(\text{BEDT-TTF})_2\text{CsZn}(\text{SCN})_4$ along the out-of-plane direction as a function of dc bias. The measured frequency and temperature are 1 MHz and 4.2 K, respectively.

by

$$\tilde{\gamma}_D = \frac{\omega_0^2 \gamma_{pD}^2 (D + i!)^2}{\gamma_{pD}^2 + \frac{2}{D}}; \quad (3)$$

where γ_{pD} and D is the plasma frequency and the damping rate, respectively. In the low-frequency limit $\omega \ll D$, the above equation reduces to

$$D = \omega_0^2 \gamma_{pD}^2 = D = \gamma_{dc} \quad (4)$$

$$\gamma_D = \omega_0^2 (1 - \gamma_{pD}^2 = \frac{2}{D}): \quad (5)$$

Since $\gamma_{pD}^2 = \frac{2}{D}$ is independent of frequency and small for the overdamped condition $D \gg \gamma_{pD}$, contribution of $\tilde{\gamma}_D$ to γ is just a small constant shift of the order of unity to γ_{LF} and γ_{HF} . Thus we can safely assume that the contribution of the Drupe conductivity appears only in the dc limit of the conductivity. In the inset of Fig. 1(a), $\gamma_b(!)$ $\gamma_b(0)$ is fitted with the Havriliak-Negami formula with the same parameters as used in $\gamma_b(!)$ through the relation of $\gamma_b(!)$ $\gamma_b(0) = \gamma_{LF} \gamma_{HF}$. The fitting curves are in excellent agreement with the measured $\gamma_b(!)$ $\gamma_b(0)$, which consolidates the validity of the Havriliak-Negami fitting.

Most unexpectedly, we have found anomalously large bias dependence of γ_b and γ_b , as shown in Fig. 2. They exhibit a jump to higher values at a critical threshold E_T of 450 V/cm with increasing electric field. The jump

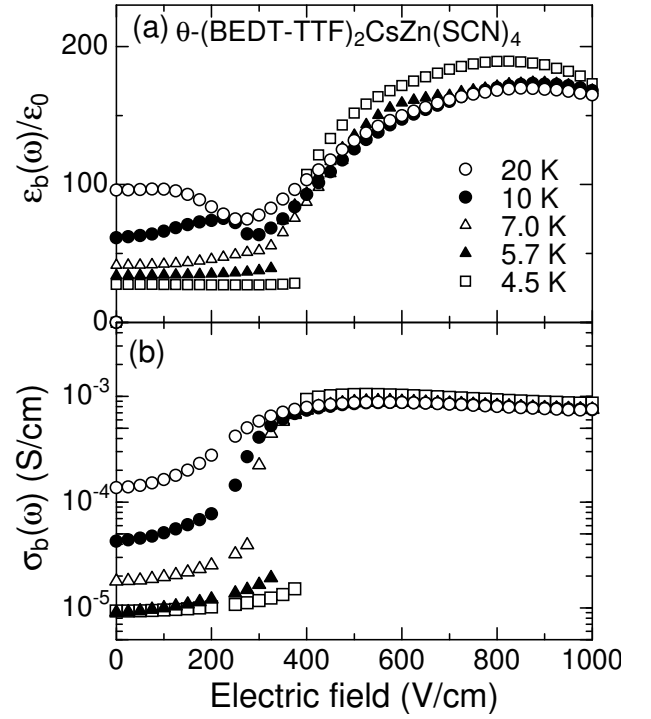


FIG. 3: (a) Dielectric constant and (b) ac conductivity at 1 MHz of $(\text{BEDT-TTF})_2\text{CsZn}(\text{SCN})_4$ along the out-of-plane direction as a function of dc bias. The data were measured with increasing electric field.

is so remarkable that γ_b increases by the two orders of magnitude, and γ_b also increases up to a large value of 200 simultaneously. Furthermore, there appears a clear hysteresis with decreasing electric field.

We should emphasize that an artifact such as heating cannot cause the abrupt jump with the significant hysteresis. We took the data with the sample immersed in liquid ^4He , and carefully evaluated the Joule heating to be a few W at the threshold, which is much smaller than a cooling power of liquid ^4He (typically more than 1 W). We should further note that a preliminary measurement using a pulse voltage technique gives identical I-V curves to those taken in static dc bias. The pulse width was changed from 2 to 50 ms with a duration time of 500 ms, and the voltage was swept from 0 to 10 V. The jump in the dc conductivity was clearly observed above 6-7 V, and the conductivity above E_T was independent of the pulse width [17]. This further supports that the heating effect is negligible above E_T .

The temperature dependence of nonlinear γ_b and γ_b is shown in Fig. 3. The data for increasing electric field are shown, (the hysteresis in Fig. 2 rapidly disappeared above 4.3 K). The large bias dependence is clearly observed up to 20 K, which suggests that the collective excitation survives at least up to 20 K. The threshold field gradually decreases with increasing temperature, but still remains finite at 20 K. Although E_T is not the

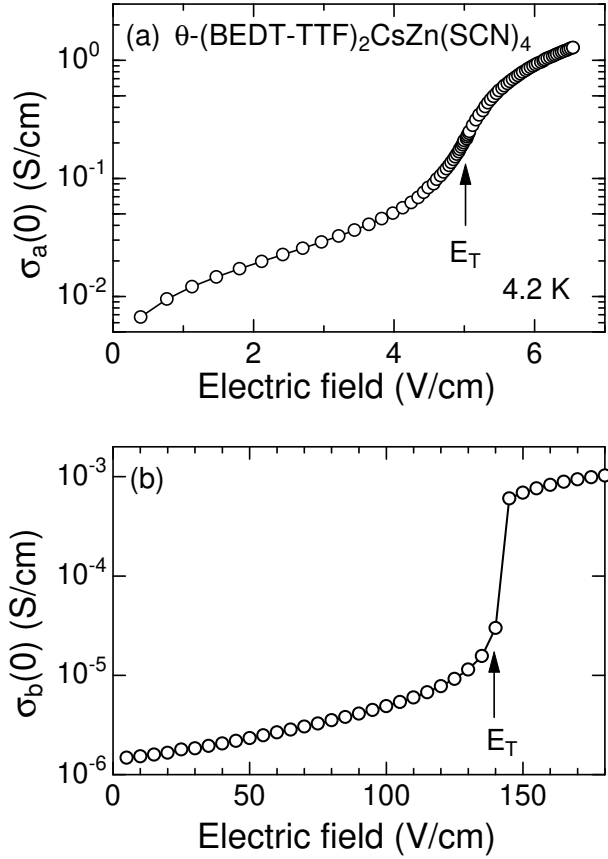


FIG. 4: Nonlinear dc conductivity of (BEDT-TTF)₂CsZn(SCN)₄ for (a) the in-plane direction and (b) the out-of-plane direction at 4.2 K plotted as a function of electric field. The data are measured with increasing electric field.

phase boundary, it can be a measure for a boundary between the metallic and insulating states, which extends to much higher temperatures. Another notable feature is that the metallic state (high-bias state) has essentially temperature-independent σ_b and σ_a . In particular, σ_b above E_T is as high as $\sigma_b(0)$ at 50 K.

In order to examine whether the large bias dependence exists only along the b direction or not, we measured the non-linear dc conductivity $\sigma(0)$ for the in-plane (a axis) direction as well as along the b direction. As clearly shown in Fig. 4, $\sigma_a(0)$ and $\sigma_b(0)$ exhibit a large non-linearity, although E_T is quite different between the two. Note that E_T along the b direction is lower than that in Fig. 2, because the sample in Fig. 4 is different from the sample in Figs. 2 and 3. E_T varies from sample to sample, but nevertheless the order of the threshold is independent of samples, which is in the range of 1-10 and 100-1000 V/cm for the a and b directions, respectively. Another notable difference is that $\sigma_a(0)$ does not show an abrupt jump, but a steep increase near E_T . It does not show a hysteresis either.

It should be emphasized that the observed giant non-linear conduction cannot be assigned to a single particle

excitation. In general, nonlinear response is observed when the electric energy gained by the applied electric field E_{ext} exceeds thermal energy $k_B T$. Then a characteristic length scale L can be estimated from the inequality $eE_{\text{ext}}L > k_B T$. In the in-plane conduction, for example, L is estimated to be $k_B T / eE_T \approx 1 \text{ nm}$ ($T = 4 \text{ K}$ and $E_T = 5 \text{ V/cm}$), which is much longer than the mean free path of the conduction electron. It is thus reasonable to assign the giant nonlinear conduction to a collective excitation with a coherent length scale of 1 nm .

IV. DISCUSSION

A. Dielectric response

As mentioned in the previous section, the large σ_b of the M=Cs salt is expressed by the dielectric relaxation. A similar σ is seen in CDW conductors such as $K_{0.3}\text{MoO}_3$ [18], in which CDW oscillates around pinning centers by an ac electric field to induce a large dielectric response. The dielectric relaxation of CDW is phenomenologically derived from the overdamped Lorentz oscillator given by

$$\epsilon''(\omega) = \epsilon'_1 + \frac{f}{\omega_0^2} \frac{\omega}{\omega^2 + \gamma^2} \quad (\omega \ll \omega_0); \quad (6)$$

where f , ω_0 , γ are the oscillator strength, the resonance frequency, and the damping rate, respectively. Equation (6) reduces to the Debye model of dielectric relaxation in the low frequency limit $\omega \ll \omega_0$ as

$$\epsilon''(\omega) = \epsilon'_1 + \frac{f}{\omega_0^2} \frac{1}{1 + \gamma^2/\omega^2} \quad (7)$$

where $\epsilon'_1 = \epsilon'_0/2$. In real materials, ϵ'' distributes significantly owing to many relaxation channels, and ϵ'' obeys the Havriliak-Negami formula given by Eq. (1).

Accordingly $(\epsilon''_{\text{LF}} - \epsilon''_{\text{HF}})/\epsilon'_0$ is equal to f/ω_0^2 , and thus the large $\epsilon''_{\text{LF}} - \epsilon''_{\text{HF}}$ implies a large f and/or a small ω_0 . In the case of the pinned CDW, f and ω_0 correspond to the Drude weight $(\epsilon''_0 \omega_p^2)$ of the order of 1 eV and the pinning potential of the order of 1 meV, respectively, which makes $(\omega_p/\omega_0)^2$ as huge as 10^6 . A more precise treatment is to solve the equation of motion for the phase of the CDW order parameter [19], which also gives the overdamped Lorentz oscillator [20].

From the viewpoint of charge density modulation, difference between CDW and CO is very subtle: the former shows a sinusoidal wave modulation, and the latter shows a square-wave modulation. In either case, the dielectric response can be described in terms of the overdamped Lorentz oscillator. In fact, charge-ordered materials such as LuFe_2O_4 [21, 22] and $\text{Pr}_{1-x}\text{Ca}_x\text{MnO}_3$ [23] show a large ϵ'' described by Eq. (1). Previously we attributed the large σ_b of the M=Rb salt to the collective motion of CO [12]. An important difference from CDW conductors is that the dielectric relaxation survives in the "normal"

TABLE I: Parameters obtained through fitting to the complex dielectric constant by a generalization of Debye's dielectric relaxation (the Havriliak-Negami formula)

	Rb ($T > T_{MI}$)	Rb ($T < T_{MI}$)	Cs
T (K)	200	140	4.3
$\tau_{LF} = \tau_0$	38	35	90
$\tau_{HF} = \tau_0$	12	12	29
	0.23	0.23	0.35
	0	0	0.15
τ (s)	0.17	500	7
(10^6 cm)	0.016	30	1

state far above T_{MI} . This means that the fluctuation of the pre-formed CO coexists with the unbound carriers that do not participate in CO. In this sense, we can say that the electrons in the $M = \text{Rb}$ salt are self-organized above T_{MI} to make its density inhomogeneous.

Since the $M = \text{Cs}$ salt is regarded as a system for $T_{MI} \neq 0$, τ_b in Fig. 1 should be compared with τ_b of the $M = \text{Rb}$ salt above T_{MI} . This picture is consistent with the x-ray diffraction study by Nogami et al. [24], where they succeeded in observing that a diffuse spot near $(0, k, 1/2)$ grows below 50 K. This indicates that the short range order of CO along the c direction grows within the BEDT-TTF layer, but no three dimensional order is realized down to 4 K. We should also note that the specific heat [25] and the susceptibility measurements [8] did not detect any jump or kink down to 4 K, implying no second-order phase (CDW/SDW/CO) transitions.

The fitting parameters of Eq. (1) are listed in Table 1. Except for τ and τ_0 , the obtained parameters are of the same order, meaning that the dynamics of CO is roughly identical. In the overdamped Lorentz model, τ is associated with the damping rate as $\tau = \hbar / \gamma$. If the damping rate is determined by the scattering between CO and the unbound conducting electron, we can expect $\tau \propto 1/n$, which roughly explains the different magnitudes of τ and τ_0 between $M = \text{Cs}$ and Rb . We further note that $\tau_{LF} = \tau_0$ for $M = \text{Cs}$ is larger than that for $M = \text{Rb}$, implying the smaller pinning frequency ω_0 as was reported in the impurity-doped CDW material [26]. This is consistent with the large bias dependence seen in Figs. 2-4. We did not see any significant nonlinear conduction for the $M = \text{Rb}$ salt.

B. Nonlinear conduction

Although nonlinear conduction is observed in various electron systems, it is rarely observed in homogeneous bulk materials, except for the flux flow resistivity of superconductors, the sliding of CDW/SDW, and the negative resistance in high-mobility semiconductors. Since the nonlinear conduction in Figs. 2-4 occurs in a low electric field of 1-100 V/cm, it should not come from a

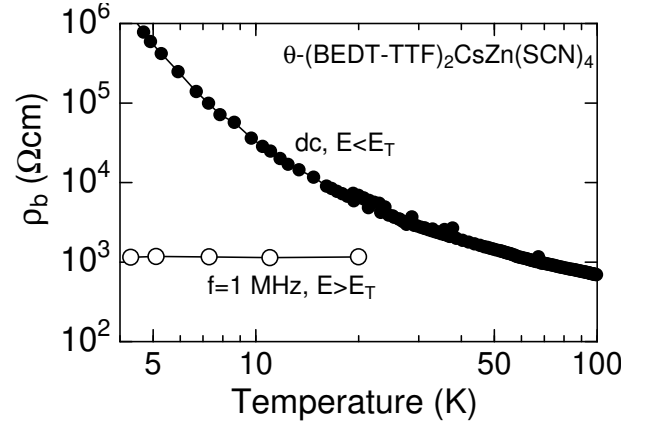


FIG. 5: Out-of-plane resistivities of $(\text{BEDT-TTF})_2\text{CsZn}(\text{SCN})_4$ for $E < E_T$ and $E > E_T$ plotted as a function of temperature.

single particle excitation, but from a collective excitation. Actually the data in Fig. 4 is similar to the nonlinear conductivity of CDW.

Let us list significant differences from the nonlinear conduction of CDW. (i) The conductivity in Figs. 4(a) and 4(b) is highly nonlinear below E_T , while most of the CDW conductors show an ohmic conductivity below E_T . This suggests that the domain sizes and/or the pinning forces of the pre-formed CO are varied widely in the $M = \text{Cs}$ salt. (ii) The CDW conductors show negligibly small nonlinear conduction above T_C . Thus it is quite surprising that the $M = \text{Cs}$ salt exhibits the huge nonlinearity of 100-1000 times above T_{MI} (< 4 K). (iii) The observed nonlinearity is much larger than that in other two-dimensional conductors [27, 28]. Large nonlinear conduction has been observed mostly in one-dimensional CDW conductors such as $\text{K}_{0.3}\text{MoO}_3$, NbSe_3 , TaS_3 [29, 30]. (iv) The nonlinear conductivity perpendicular to the charge-density modulation is observed for the first time.

Figure 5 shows the dc resistivity along the b axis (ρ_b) below E_T plotted as a function of temperature. ρ_b increases with decreasing temperature, the temperature dependence of which is nearly the same as that of the in-plane (the a axis) resistivity (ρ_a) [8]. This indicates that the insulating state is more or less three-dimensional. The low-temperature upturn in ρ_a has been understood in terms of variable range hopping (VRH) | strongly localized state, but it should be emphasized here that the frequency and temperature dependences of ρ_a and ρ_b seriously contradict the VRH picture. In Fig. 5, ρ_b (1 MHz) for $E > E_T$ is also plotted as a function of temperature, which is nearly the same value of ρ_b at 60 K. This means that the $M = \text{Cs}$ salt at low temperature is a "fake" insulator that is quite unstable against the strong electric field. Wang et al. observed an anomalous increase in ρ_a (!) of the $M = \text{Cs}$ salt in the infrared region at low temperatures, and speculated that the $M = \text{Cs}$ salt is in the verge of metal-insulator transition [32], which

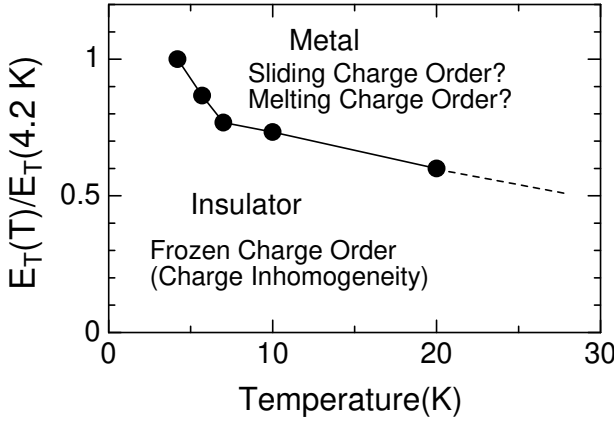


FIG. 6: Electronic pseudo-phase diagram for $(\text{BEDT-TTF})_2\text{CsZn}(\text{SCN})_4$

might be associated with the fake insulating state.

The nonlinear conduction below E_T is usually weak in the CDW materials. A homogeneous CDW order has a single coherent length, and the corresponding value of E_T is uniquely determined. On the contrary, the $M = \text{Cs}$ salt exhibits the nonlinear conduction for $E < E_T$ as shown in Fig. 4, which naturally implies a larger scale of the CO domain. Imagine that the CO domains form a percolative network in a fractal dimension. Then a larger cluster can move for a smaller electric field, and the number of the mobile clusters gradually increase with increasing field. This picture is consistent with the charge inhomogeneity in the high-temperature superconductor [1].

The most puzzling finding is the large hysteresis of ρ and ρ_{eff} shown in Fig. 2. At first glance, this resembles the switching behavior of $\text{K}_{0.3}\text{MnO}_3$ [29], which was phenomenologically understood in terms of the damping rate depending on the CDW sliding velocity [33]. However, the electric field was perpendicular to the charge modulation in the present case, and we cannot expect the sliding of CO across the layers. We cannot expect either that a CO domain hops from one layer to other, because it requires enormous numbers of electrons to tunnel simultaneously. We should further note that ρ above E_T decreases with increasing bias voltage for conventional CDW conductors [30], which is seriously incompatible with the data in Fig. 2(a).

Finally we will append a note that we have found a similar bias dependence in the dc conductivity of $(\text{BEDT-TTF})_2\text{CsCo}(\text{SCN})_4$, which has nearly the same structure as $(\text{BEDT-TTF})_2\text{CsZn}(\text{SCN})_4$. This strongly suggests that the giant nonlinear conduction is a generic feature for some β -type salts [17].

C. Inhomogeneity in a homogeneous system

As mentioned in the Introduction, the organic salts are one of the cleanest solids currently available, in

which point defects, dislocations and solid solutions are expected to be negligibly small. Nevertheless, a for $M = \text{Cs}$ is $30 \text{ m}\mu\text{m}$ at 300 K [8], which is indeed anomalously high. In a two-dimensional conductor, the mean free path ℓ is directly evaluated from the in-plane resistivity through the relation

$$k_F \ell = \hbar c_0 / e^2 a; \quad (8)$$

where c_0 is the interlayer spacing [34]. Then $30 \text{ m}\mu\text{m}$ gives $k_F \ell = 0.1$, and such a short ℓ is difficult to understand in the clean system. The metallic behavior ($d\rho/dT > 0$) at 300 K is also difficult to understand, because the de Broglie wavelength of the conducting electron is much shorter than ℓ for $k_F \ell \ll 1$.

We can clear up these difficulties, if the electronic states of the $M = \text{Cs}$ salt are spatially inhomogeneous, because Eq. (8) is derived for a homogeneous system. Suppose most of the conduction electrons are nearly frozen to form CO domains, and the unbound electrons flow in a percolation network consisting of the domain boundaries. Then the effective cross section for the current path is much smaller than the bulk cross section of the sample, and the "apparent" resistivity would be much higher. If $k_F \ell$ is still larger than unity in the current path, the conduction can be metallic to cause $d\rho/dT > 0$. Judging from the anomalously high in-plane resistivity, we think that the self-organization of the electrons in $M = \text{Cs}$ readily starts even at room temperature. Then the self-organized CO is gradually frozen with decreasing temperature, and eventually shows the CDW-like collective excitation.

Let us discuss the reason why the self-organized inhomogeneity is realized in the β -type salts. Mori [35] calculated the ground-state energy for the β -type salts using the extended Hubbard model, and discussed possible CO patterns at finite temperatures. He found that the on- and off-site Coulomb repulsions are of the same order, and their delicate balance causes various CO patterns. In particular, "horizontal", "diagonal" and "3-fold" patterns are nearly degenerate in the $M = \text{Cs}$ salt, and thus it is highly probable that different charge orders coexist. Furthermore, these charge orders would be strongly coupled with phonons, as was evidenced by the strong Fano effects in the infrared spectroscopy [14, 32]. Thus CO domains of different patterns store finite elastic energies, which prevents the domains to grow in size [36]. As a result, homogeneous phase transition is seriously suppressed, and the domains are frozen at low temperatures like polar nano-regions in relaxor ferroelectrics [37]. We therefore expect that the $M = \text{Cs}$ salt can be a canonical material showing the intrinsic inhomogeneity in the electron density.

A remaining issue is up to what temperature the collective excitation can be observed. Figure 6 shows E_T in Fig. 3(b) as a function of temperature. Clearly, the phase boundary would exist above 20 K . If we extrapolate the data to higher temperatures as indicated by the dotted line, we can estimate the temperature for $E_T = 0$

to be 65 K, which is roughly the same temperature at which $1=\nu_b$ (1 MHz) in the high-bias state is equal to ν_b in Fig. 5. To measure E_T at higher temperatures, we should employ a pulse generator to avoid the Joule heating, which will be tried in future work.

The metallic state above $E > E_T$ is not yet understood. In CDW conductors, the high-biased state is the state that CDW is sliding with a finite damping from the normal electrons, which has been established from the diffraction experiment in high electric fields. In the present case, the $M=Cs$ salt only has the short range order of CO, where the phase of CO acquires no rigidity. Then the sliding of CO is difficult to expect. Another choice is the melting of CO by electric field, like the vortex lattice melting by magnetic field in a type-II superconductor. To clarify this problem, diffraction measurements in electric fields are indispensable, and microscopic theory to explain our findings is also necessary.

V. SUMMARY

We have observed the large dielectric response and giant nonlinear conduction in (BEDT- TTF)₂CsZn(SCN)₄.

The data resemble those for charge-density-wave (CDW) conductors such as $K_{0.3}MoO_3$. However, (BEDT- TTF)₂CsZn(SCN)₄ shows no second-order transition down to 4 K, which implies that it exhibits CDW-like collective excitations in the "normal" state. Therefore we expect that this material can belong to a new hierarchy of condensed matter, in which conduction electrons are self-organized to have collective modes without long range order.

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